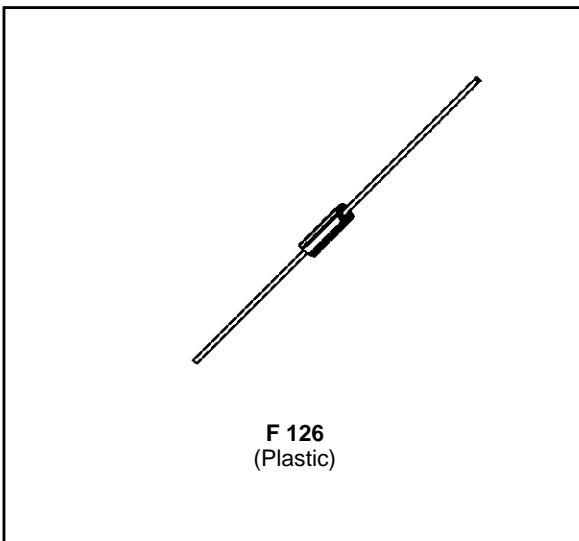


FAST RECOVERY RECTIFIER DIODES

- SOFT RECOVERY
- VERY HIGH VOLTAGE
- SMALL RECOVERY CHARGE



APPLICATIONS

- ANTISATURATION DIODES FOR TRANSISTOR BASE DRIVE
- SNUBBER DIODES

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
I_{FRM}	Repetitive Peak Forward Current	20	A
$I_F(AV)$	Average Forward Current *	1	A
I_{FSM}	Surge non Repetitive Forward Current	35	A
P_{tot}	Power Dissipation *	1.25	W
T_{stg} T_j	Storage and Junction Temperature Range	- 55 to + 150 - 55 to + 150	°C
T_L	Maximum Lead Temperature for Soldering during 10s at 4mm from Case	230	°C

Symbol	Parameter	BYT 11-			Unit
		600	800	1000	
V_{RRM}	Repetitive Peak Reverse Voltage	600	800	1000	V

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
$R_{th(j-a)}$	Junction-ambient*	60	°C/W

* On infinite heatsink with 10mm lead length.

ELECTRICAL CHARACTERISTICS**STATIC CHARACTERISTICS**

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
I_R	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			20	μA
V_F	$T_j = 25^\circ\text{C}$	$I_F = 1\text{A}$			1.3	V

RECOVERY CHARACTERISTICS

Symbol	Test Conditions				Min.	Typ.	Max.	Unit
t_{rr}	$T_j = 25^\circ\text{C}$	$I_F = 0.5\text{A}$	$I_R = 1\text{A}$	$I_{rr} = 0.25\text{A}$			100	ns

To evaluate the conduction losses use the following equations:

$$V_F = 1.1 + 0.075 I_F \quad P = 1.1 \times I_{F(AV)} + 0.075 I_{F(RMS)}^2$$

Figure 1. Maximum average power dissipation versus average forward current.

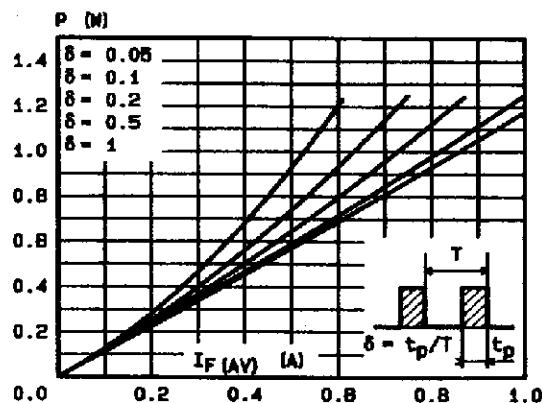


Figure 2. Average forward current versus ambient temperature.

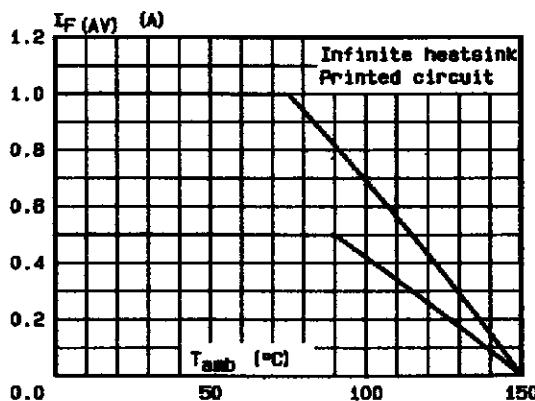
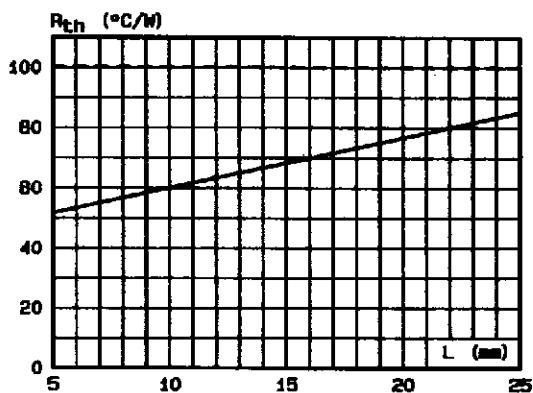
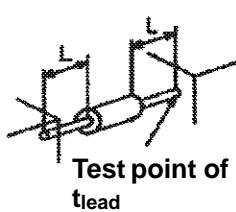


Figure 3. Thermal resistance versus lead length.



**Mounting n°1
INFINITE HEATSINK**



**Mounting n°2
PRINTED CIRCUIT**

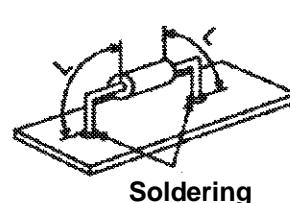


Figure 4. Transient thermal impedance junction-ambient for mounting n°2 versus pulse duration ($L = 10$ mm).

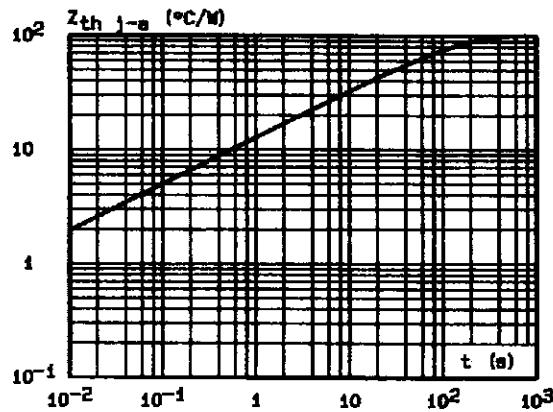


Figure 6. Capacitance versus reverse applied voltage

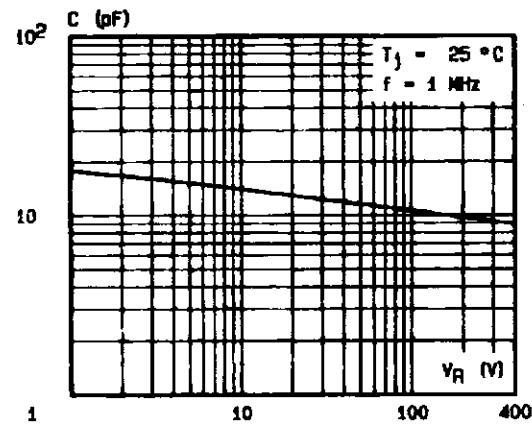


Figure 5. Peak forward current versus peak forward voltage drop (maximum values).

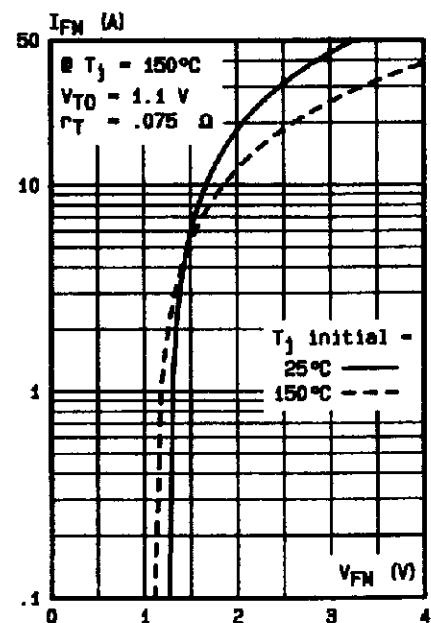
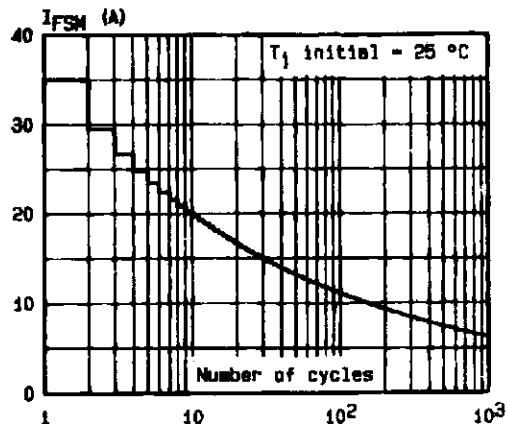
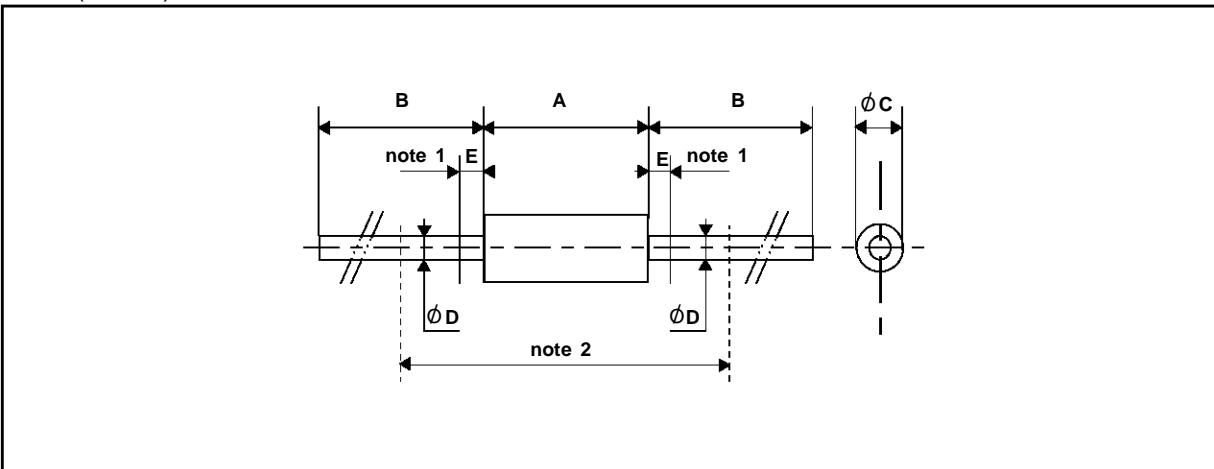


Figure 7. Non repetitive surge peak current versus number of cycles



PACKAGE MECHANICAL DATA

F 126 (Plastic)



REF.	DIMENSIONS				NOTES	
	Millimeters		Inches			
	Min.	Max.	Min.	Max.		
A	6.05	6.35	0.238	0.250	1 - The lead diameter $\emptyset D$ is not controlled over zone E	
B	26		1.024		2 - The minimum axial length within which the device may be placed with its leads bent at right angles is 0.59" (15 mm)	
$\emptyset C$	2.95	3.05	0.116	0.120		
$\emptyset D$	0.76	0.86	0.029	0.034		
E		1.27		0.050		

Cooling method: by convection (method A)

Marking: type number ring at cathode end

Weight: 0.4g

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